	Application No. Applicant(s)		
Notice of Allowability	10/602 647		
	10/693,647 Examiner	JUNG ET AL	UT
		Art Unit	
J	John S. Chu	1752	
The MAILING DATE of this communication appe All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIG	or other appropriate comm	in this application. If not include	d
1. This communication is responsive to <u>10/27/03</u> .			
2. The allowed claim(s) is/are <u>1-21</u> .			
3. The drawings filed on 10/27/03 are accepted by the Examin	er.		
<ul> <li>4.   Acknowledgment is made of a claim for foreign priority und</li> <li>a)   All b)   Some* c)   None of the:</li> <li>1.   Certified copies of the priority documents have</li> </ul>		or (f).	
2. Certified copies of the priority documents have	been received in Application	on No	
3. Copies of the certified copies of the priority doci	uments have been receive	d in this national stage and and	
International Bureau (PCT Rule 17.2(a)).		d in this national stage application	on from the
* Certified copies not received:			
Applicant has THREE MONTHS FROM THE "MAILING DATE" or noted below. Failure to timely comply will result in ABANDONME THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.	f this communication to file NT of this application.	a reply complying with the requ	irements
5. A SUBSTITUTE OATH OR DECLARATION must be submitt INFORMAL PATENT APPLICATION (PTO-152) which gives	reason(s) wny the oath or	AMINER'S AMENDMENT or NO declaration is deficient.	TICE OF
6. CORRECTED DRAWINGS (as "replacement sheets") must	be submitted.		
<ul><li>(a) ☐ including changes required by the Notice of Draftspersor</li></ul>	n's Patent Drawing Review	v ( PTO-948) attached	
) ☐ nereto or 2) ☐ to Paper No./Mail Date			
(b) ☐ including changes required by the attached Examiner's A Paper No./Mail Date			
Identifying indicia such as the application number (see 37 CFR 1.84 each sheet. Replacement sheet(s) should be labeled as such in the	4(c)) should be written on the	ne drawings in the front (not the ba	ack) of
7. DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT FO	of DIOLOGICAL MATE		e the
Attachment(s)			
1. Notice of References Cited (PTO-892)	5. Notice of Info	ormal Patent Application (PTO-1	52)
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	6. 🔲 Interview Su	mmary (PTO-413),	<i>32)</i>
3. ☑ Information Disclosure Statements (PTO-1449 or PTO/SB/08), Paper No./Mail Date 4/1/04	Paper No./N	Paper No./Mail Date 7.  Examiner's Amendment/Comment	
4. Examiner's Comment Regarding Requirement for Deposit	8. 🛛 Examiner's S	Statement of Reasons for Allowa	nce
of Biological Material	9. 🗌 Other		
		,	

Art Unit: 1752

## REASONS FOR ALLOWANCE

- 1. The following is an examiner's statement of reasons for allowance: The claimed invention is drawn to the following:
  - A method for forming a carbon nanotube pattern, comprising:
  - (a) surface treating a substrate to expose amino groups thereon;
  - (b) treating the surface-treated substrate with a linker of aminoalkylcarboxylic acid represented by the following formula 1:

Formula 1

wherein R is a functional group capable of being dissociated by an acid, and n is an integer of 1 to 50, in the presence of a coupling agent to form amide bonds between the amino groups exposed on the substrate and the carboxyl groups of the aminoalkylcarboxylic acid;

- (c) applying a photo-acid generator onto the substrate, irradiating UV light to the substrate through a patterned photomask, and developing with an alkaline developer to form a positive pattern on which reactive amino groups are exposed; and
- (d) reacting the reactive amino groups on the substrate with carboxylated carbon nanotubes in the presence of a coupling agent to form a carbon nanotube layer.
  - A method for forming a carbon nanotube layer, comprising:
- (a) surface treating a substrate to expose amino groups thereon;

Application/Control Number: 10/693,647

Art Unit: 1752

(b) reacting the amino groups of the substrate with carboxylated carbon nanotubes in the presence of a coupling agent and a catalyst to form a carbon nanotube layer,

wherein the coupling agent is O-(7-azabenzotriazol-1-yl)-N,N,N',N'-tetramethyluronium hexafluorophosphate and the catalyst is alkyl or aryl amine.

The claimed method recited in claim 1, as paraphrased by the examiner, discloses forming amide bonds between carboxylate carbon nanotubes and a substrate having amino groups that are exposed after being cleaved with a photo-acid generatoring compound. Step (c) applies a photoacid-generating compound on said substrate, which is then exposed and developed to leave a positive pattern having functional and reactive amino groups in the exposed areas. The subsequent step (d) covalently bonds the carbon nanotube to the substrate surface.

None of the references of record disclose the two processes recited above.

Claim 14 recites a coating process for forming a layer of carbon nanotubes on a substrate. Here again the process is forming a covalent bond between the amino groups of the substrate with carboxylate carbon nanotubes using a specific coupling agent.

None of the prior art references of record disclose the recited process of forming a layer of carbon nanotubes on a substrate as claimed.

LAVIN et al disclose forming carbon nanotube composites wherein the carbon nanotubes are reacted with a diamine, however the reference fails to discloses photolithographic process as recited in claim 1 or the forming of a layer with a specified coupler as recited in claim 14.

ZHOU et al disclose the use of depositing carbon nanotubes on a substrate, however they use a substrate having an -OH group to form a film, which is different form the amide bond forming reaction claimed here. ZHOU et al further discloses coating method of patterned carbon

Application/Control Number: 10/693,647

Art Unit: 1752

nanotubes on a glass substrate, however their methods do not disclose the claimed amide bond forming method as currently claimed.

CHENG discloses patterning thick film by coating a thick film paste over a photoresist pattern. The references fails to disclose the method of forming a carbon nanotube layer as claimed.

SMITS et al disclose depositing carbon nanotubes and aligning them with an electric field. This is also different than the claimed coating method recited.

Accordingly, claims 1-21 are seen as allowable over the prior art of record and passed to issue.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

2. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. EP 1,457,821 to the same assignee discloses methods of making carbon nanotube patterns, however the publication date is after the filing date of the current application (October 27, 2003) and is not proper prior art.

EP 1,422,563 to the same assignee and published May 26, 2004 is not prior art.

3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Examiner Chu whose telephone number is (571) 272-1329. The examiner can normally be reached on Monday - Friday from 9:30 am to 6:00 pm.

The fax phone number for the USPTO is (703) 872-9306.

Art Unit: 1752

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the Group receptionist whose telephone number is (571) 272-1700.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PMR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

ohn S. Chu

Primary Examiner, Group 1700

J.Chu December 12, 2004